NSN 5961-00-088-2715

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-088-2715 **Inclosure Material:** Metal **Overall Length:** Between 0.015 inches and 0.025 inches **Overall Diameter:** Between 0.118 inches and 0.122 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 10.00 microamperes breakover current, dc **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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